SURFACE MOUNT-CERAMIC

ATTENUATOR, PIN DIODE

0.8-4 GHz

GENERAL INFORMATION

The PI-800 Se ies atten uators are pat tof the rew Surfpac product line featuring good intermodulation performance compared to their GaAs counter parts for PCS/cellular base station use. In addition, the PIN diodes off er good power-handling capabilities and are less sensitive to electrostatic discharge pto lems. Thesef eatures are impotant considerations in base station applications where the effects of antennarelated RFs witching and indirect lightning-induced/ oltage spik es are present.

PIN diode components to ve inherent advantages over the GaAs alternatives at PCS/cellular frequencies. The PI-800 Series attenuator makes use of these advantages in a to w cost sufface-mount parkage suitable for pick-and-place applications. As a result, the attentuator satisfies both the technical specifications and the manufacturing requirements of tool y's demanding commercial maketplace.

PIN diodes are widely accepted as more robust alter natives to GaAs FETs and of er higher isolation with 6 wer insertion loss than plastic packaged GaAs attre uators at Personal Communications Service (PCS) frequencies. The PI-800 Series analog attre uator incorporates PIN diodes with highly reliable thick-film technology and sufrace mount components on a miniatureol w cost sealed sufrace mount alumina header. This new attenuator provides a good match, flat attre uation and overall superior performance over the 0.8-4 GHz frequency range, and can be optimal edo ver lower frequency ranges.

GENERAL SPECIFICATIONS

Frequency Range:	10% B .W. Typical, 0.8–4 GHz				
Insertion Loss:	Per chart				
Attenuation Range:	Per chart				
Control Voltage:	0-5 VDC				
1 dB Compression Point:	+27 dBm				
Construction:	Thick film alumina with epo xy sealed				
	cover				
Speed:	2 µsec				
Temperature:	-10 to +80°C. See application note for recommended maximum reflow soldering temperatures.				

SERIES PI-800

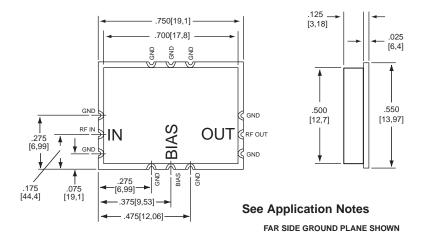


FEATURES

- Low Loss
- · Low I.M. products
- PIN diode performance
- Low VSWR
- 500 mw power
- · Pick and place and reflow manufacture
- · Shunt diode design

	Insertion						
	Frequency	Attenuation	Loss (dB)	VSWR	Typical		
Model	(GHz)	Range (dB)	Maximum	Maximum	Current(mA)		
PI-820NS	1.84-1.94	0-6	0.7	1.50	30		
PI-840	0.8-1.0	0-35	0.5	1.40	50		
PI-850	0.8-1.0	0-30	1.0	1.50	50		
PI-845	1.7-2.0	0-35	0.8	1.50	50		
PI-855	1.7-2.0	0-25	1.0	1.50	50		
PI-A05	2.4-2.46	0-20	1.3	1.50	50		
PI-A04	3.55-3.65	0-25	1.5	1.50	50		
PI-A06	3.5-4.0	0-20	1.5	1.50	50		

OUTLINE-PI-800 SERIES



KE YInches[Millimeters] .XX ±.03 .XXX ±.010 [.X ±0.8 .XX ±0.25]



